

Technical Data Data Sheet N1036, Rev. -

Green Products

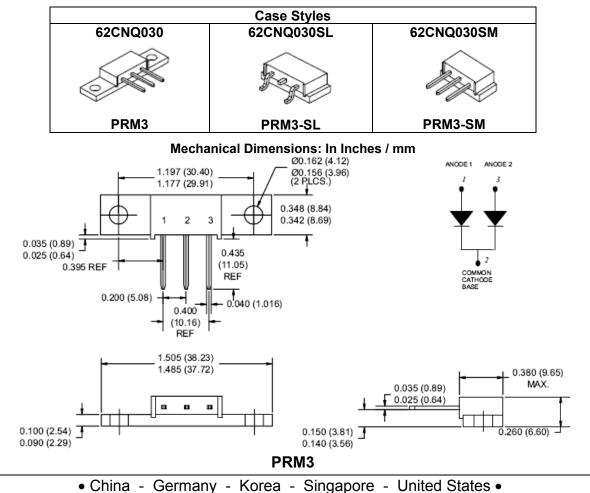
62CNQ030 SCHOTTKY RECTIFIER

Applications:

- Switching power supply
- Converters
 - Free-Wheeling diodes
- Reverse battery protection

Features:

- 150℃ T_J operation
- Center tap module
- Very Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Low profile, high current package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

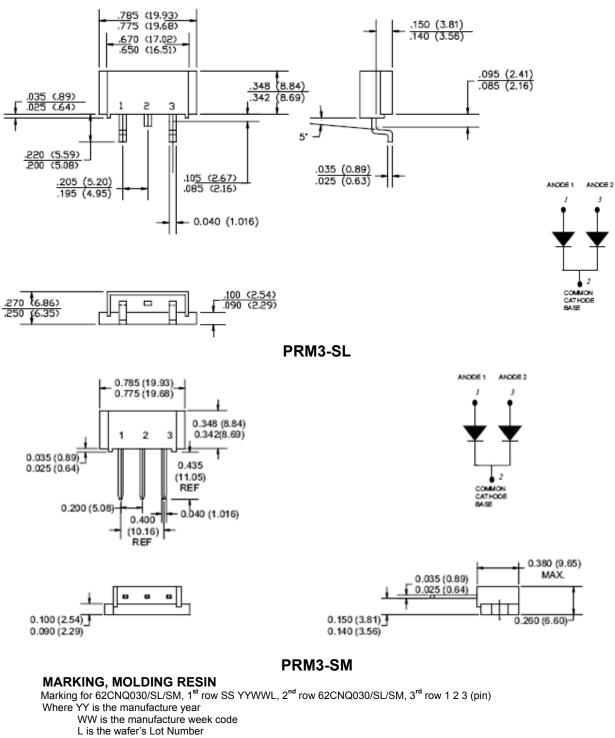


• http://www.smc-diodes.com - sales@ smc-diodes.com •



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Molding resin Epoxy resin UL: 94V-0

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Ordering Information:

Device	Package	Terminals finish	Shipping
62CNQ030	PRM3	Nickel plated	48pcs / box
62CNQ030S	PRM3	Pure Sn dipped (dipped height 6-8 mm)	48pcs / box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	30	V
Average Rectified Forward Current	I _{F(AV)}	50% duty cycle @T _c =135°C, rectangular wave form	60	А
Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	940	A
Non-Repetitive Avalanche Energy(peg leg)	E _{AS}	T _J =25℃,I _{AS} =6A,L=1.5mH	27	mJ
Repetitive Avalanche Current(peg leg)	I _{AR}	Current decaying linearly to zero in 1 μ sec Frequency limited by T _J max. V _A =1.5 × V _R typical	6	A



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Electrical Characteristics:

Characteristics	Symbol	Condition	_ Тур	Max.	Units
Forward Voltage Drop (per leg) *	V _{F1}	@ 30A, Pulse, T _J = 25 °C @ 60A, Pulse, T _J = 25 °C	0.43 0.48	0.49 0.53	V
	V _{F2}	@ 30A, Pulse, T _J = 125 °C @ 60A, Pulse, T _J = 125 °C	0.32 0.36	0.35 0.44	V
Reverse Current (per leg) *	I _{R1}	$@V_R = rated V_R T_J = 25 °C$	0.18	5	mA
	I _{R2}	$@V_R = rated V_R T_J = 125 \circ C$	170	280	mA
Junction Capacitance (per leg)	C _T	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	2900	3700	pF
Series Inductance (per leg)	L _S	Measured lead to lead 5 mm from package body	6.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse Width < 300µs, Duty Cycle <2%

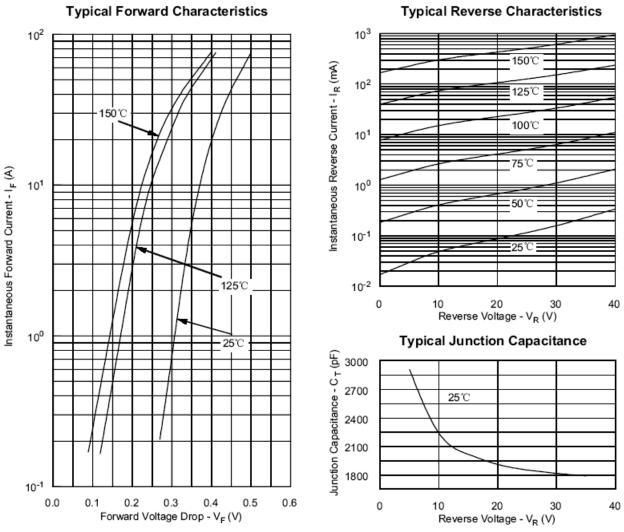
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units	
Junction Temperature	TJ	-	-55 to +150	О°	
Storage Temperature	T _{stg}	-	-55 to +150	°C	
Typical Thermal Resistance Junction to Case (per leg)	$R_{ ext{ heta}JC}$	DC operation	0.85	°C/W	
Typical Thermal Resistance Junction to Case (per package)	$R_{ ext{ heta}JC}$	DC operation	0.42	°C/W	
Typical Thermal Resistance, case to Heat Sink	R _{θcs}	Mounting surface, smooth and greased	0.30	°C/W	
Mounting Torque	Тм	-	40(min)	Kg-cm	
			58(max)	Ng-Cill	
Approximate Weight	wt	-	7.8	g	
Case Style	PRM3 PRM3-SL PRM3-SM				



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62CNQ030

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